NSN 5961-01-478-4342

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Semiconductor Material:

Silicon alloy

Voltage Rating In Volts Per Characteristic:

38.0 breakdown voltage, collector-to-base, emitter open and 18.0 breakdown voltage, collector-to-emitter, base open and 4.0 breakdown voltage, emitter-to-base, collector open

Current Rating Per Characteristic:

Between 500.00 milliamperes source cutoff current and 1000.00 milliamperes source cutoff current and 0.25 milliamperes zero-gate-voltage source current preset

Power Rating Per Characteristic:

12.0 watts small-signal input power, common-emitter peak

Transfer Ratio:

5.0 static forward current transfer ratio, common-emitter

Special Features:

derate j to c 68.0 milliwatts; on-state current 50 megahertz; part name assigned by controlling agency - silicon npn power transistor

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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